## NSN 5962-01-249-0340

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View Online at https://aerobasegroup.com/nsn/5962-01-249-0340 **Body Length:** 1.290 inches **Body Width:** 0.610 inches **Body Height:** 0.150 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and bipolar and programmable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 13 input **Case Outline Source And Designator:** D-3 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 49956-954374 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure:** 

Yes - demil/mli

Demilitarization:

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